INTEGRATED CIRCUITS



Product specification Supersedes data of 2004 Mar 10 2004 Mar 22





# 74LVC38A

### FEATURES

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Open-drain outputs
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- Specified from -40 to +85 °C and -40 to +125 °C.

### DESCRIPTION

The 74LVC38A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC38A provides the 2-input NAND function.

The outputs of the 74LVC38A devices are open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb}$  = 25 °C;  $t_r$  =  $t_f$   $\leq$  2.5 ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PZL</sub>	propagation delay nA, nB to nY	$C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	1.7	ns
t <sub>PLZ</sub>	propagation delay nA, nB to nY	$C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	2.3	ns
CI	input capacitance		4.0	рF
C <sub>PD</sub>	power dissipation capacitance per gate	$V_{CC}$ = 3.3 V; notes 1 and 2	5.5	pF

### Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

2. The condition is  $V_I = GND$  to  $V_{CC}$ .

### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE							
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE			
74LVC38AD	–40 to +125 °C	14	SO14	plastic	SOT108-1			
74LVC38ADB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1			
74LVC38APW	–40 to +125 °C	14	TSSOP14	plastic	SOT402-1			
74LVC38ABQ	−40 to +125 °C	14	DHVQFN14	plastic	SOT762-1			

# 74LVC38A

## FUNCTION TABLE

See note 1.

INP	OUTPUTS	
nA nB		nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

### Note

1. H = HIGH voltage level;

L = LOW voltage level:

Z = high-impedance OFF-state.

## PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1B	data input
3	1Y	data output
4	2A	data input
5	2B	data input
6	2Y	data output
7	GND	ground (0 V)
8	3Y	data output
9	3A	data input
10	3B	data input
11	4Y	data output
12	4A	data input
13	4B	data input
14	V <sub>CC</sub>	supply voltage

# 74LVC38A



# 74LVC38A



## **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage	for maximum speed performance	2.7	3.6	V
		for low-voltage applications	1.2	3.6	V
VI	input voltage		0	5.5	V
Vo	output voltage		0	5.5	V
T <sub>amb</sub>	operating ambient temperature		-40	+125	°C
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{ V}$	0	20	ns/V
		$V_{CC} = 2.7$ to 3.6 V	0	10	ns/V

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input diode current	V <sub>1</sub> < 0	_	-50	mA
VI	input voltage	note 1	-0.5	+6.5	V
I <sub>OK</sub>	output diode current	V <sub>O</sub> < 0	-	-50	mA
Vo	output voltage	note 1	-0.5	+6.5	V
lo	output sink current	$V_{O} = 0$ to $V_{CC}$	-	50	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		-	±100	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	power dissipation	$T_{amb} = -40$ to +125 °C; note 2	_	500	mW

### Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. For SO14 packages: above 70 °C derate linearly with 8 mW/K.

For (T)SSOP14 packages: above 60  $^\circ\text{C}$  derate linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60  $^\circ\text{C}$  derate linearly with 4.5 mW/K.

# 74LVC38A

### DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS					
		OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	
T <sub>amb</sub> = -40	<b>) to +85</b> ° <b>C;</b> note 1		I	_	-	-	
V <sub>IH</sub>	HIGH-level input voltage		1.2	V <sub>CC</sub>	-	_	V
			2.7 to 3.6	2.0	-	_	V
V <sub>IL</sub>	LOW-level input voltage		1.2	_	-	GND	V
			2.7 to 3.6	_	-	0.8	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I <sub>O</sub> = 100 μA	2.7 to 3.6	_	GND	0.20	V
		I <sub>O</sub> = 12 mA	2.7	_	_	0.40	V
		I <sub>O</sub> = 24 mA	3.0	_	_	0.55	V
ILI	input leakage current	V <sub>I</sub> = 5.5 V or GND	3.6	_	±0.1	±5	μA
I <sub>OZ</sub>	3-state output OFF-state	$V_{I} = V_{IH} \text{ or } V_{IL};$	3.6	_	0.1	±10	μA
	current	$V_0 = 5.5 V \text{ or GND}$					
I <sub>CC</sub>	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$	3.6	-	0.1	10	μA
$\Delta I_{CC}$	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0$	2.7 to 3.6	-	5	500	μA
T <sub>amb</sub> = -40	) to +125 °C						
VIH	HIGH-level input voltage		1.2	V <sub>CC</sub>	_	_	V
			2.7 to 3.6	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		1.2	_	_	GND	V
			2.7 to 3.6	_	-	0.8	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$					
		I <sub>O</sub> = 100 μA	2.7 to 3.6	_	_	0.3	V
		I <sub>O</sub> = 12 mA	2.7	_	_	0.6	V
		I <sub>O</sub> = 24 mA	3.0	_	_	0.8	V
ILI	input leakage current	V <sub>I</sub> = 5.5 V or GND	3.6	_	-	±20	μA
I <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$	3.6	-	-	±20	μA
I <sub>CC</sub>	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$	3.6	_	-	40	μA
$\Delta I_{CC}$	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0$	2.7 to 3.6	-	-	5000	μA

### Note

1. All typical values are measured at V\_{CC} = 3.3 V and T\_{amb} = 25 °C.

# 74LVC38A

## AC CHARACTERISTICS

 $GND = 0 V; t_r = t_f \le 2.5 ns.$ 

SYMBOL	PARAMETER	TEST CONDITIONS					
		WAVEFORMS	V <sub>CC</sub> (V)	– MIN.	TYP	MAX.	UNIT
T <sub>amb</sub> = -40	<b>) to +85</b> ° <b>C</b> ; note 1			•			
t <sub>PZL</sub>	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	-	5.7	-	ns
			2.7	0.5	1.7	2.9	ns
			3.0 to 3.6	0.5	1.7 <sup>(2)</sup>	3.0	ns
t <sub>PLZ</sub>	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	_	4.8	_	ns
			2.7	1.0	2.6	3.8	ns
			3.0 to 3.6	1.0	2.3(2)	3.6	ns
t <sub>sk(0)</sub>	skew	note 3		_	_	1.0	ns
T <sub>amb</sub> = -40	) to +125 °C		•	•		•	·
t <sub>PZL</sub>	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	-	-	-	ns
			2.7	0.5	_	4.0	ns
			3.0 to 3.6	0.5	_	4.0	ns
t <sub>PLZ</sub>	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	_	_	_	ns
			2.7	1.0	_	5.0	ns
			3.0 to 3.6	1.0	_	4.5	ns
t <sub>sk(0)</sub>	skew	note 3		-	_	1.5	ns

Notes

1. All typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

2. These typical values are measured at  $V_{CC}$  = 3.3 V.

3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

# 74LVC38A

### AC WAVEFORMS





### Note

1. The circuit performs better when  $R_L = 1000 \Omega$ .

Definitions for test circuits:

R<sub>L</sub> = Load resistor.

 $C_{\text{L}}$  = Load capacitance including jig and probe capacitance.

 $R_{T}$  = Termination resistance should be equal to the output impedance  $Z_{o}$  of the pulse generator.

 $t_{r}$  =  $t_{f}$   $\leq$  2.5 ns; when measuring  $f_{max},$  there is no constraint on  $t_{r},\,t_{f}$  with 50% duty factor.

Fig.7 Load circuitry for switching times.

### PACKAGE OUTLINES



74LVC38A

#### SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm SOT337-1 Α D X \_\_\_\_у = v M A HE -Z+ 14 🗍 Q A<sub>2</sub> 4 $(A_3$ pin 1 index Lp H Ш Π detail X • († w (M) ►' b<sub>p</sub> е 2.5 5 mm 0 scale DIMENSIONS (mm are the original dimensions) Α D<sup>(1)</sup> E<sup>(1)</sup> Z<sup>(1)</sup> UNIT L Q θ Α<sub>1</sub> $A_2$ $A_3$ bp С е $H_{\rm E}$ Lp ۷ w у max 0.21 1.80 0.38 0.20 6.4 1.03 8° 5.4 7.9 0.9 1.4 2 0.13 0.1 mm 0.25 0.65 1.25 0.2 0° 0.05 1.65 0.25 0.09 6.0 5.2 7.6 0.63 0.7 0.9 Note 1. Plastic or metal protrusions of 0.25 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE ISSUE DATE VERSION PROJECTION IEC JEDEC JEITA 99-12-27 SOT337-1 MO-150 03-02-19

#### TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm SOT402-1 А D Х = v ₪ A HE + Z 8 || Q $(A_{3})$ A2 A<sub>1</sub> pin 1 index -p detail X **-** ⊕ w M е bp 2.5 0 5 mm scale DIMENSIONS (mm are the original dimensions) Α E <sup>(2)</sup> D<sup>(1)</sup> Z <sup>(1)</sup> UNIT L Q θ $A_1$ A<sub>2</sub> A<sub>3</sub> bp С е ${\rm H_{\rm E}}$ Lp v w у max 0.95 0.30 0.75 8° 0.15 0.2 5.1 4.5 6.6 0.4 0.72 0.65 0.2 0.1 mm 1.1 0.25 1 0.13 0.05 0.80 0.19 0.1 4.3 6.2 0.50 0.3 0° 4.9 0.38 Notes 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE **ISSUE DATE** VERSION PROJECTION IEC JEDEC JEITA 99-12-27 SOT402-1 MO-153 03-02-18

# 74LVC38A

74LVC38A



### DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

74LVC38A

### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

### DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

**Right to make changes** — Philips Semiconductors reserves the right to make changes in the products including circuits, standard cells, and/or software described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

# Philips Semiconductors – a worldwide company

### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2004

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

R20/03/pp14

Date of release: 2004 Mar 22

Document order number: 9397 750 13029

SCA76

Let's make things better.





Philips Semiconductors